

Pb Free Plating Product

2SK4107



THINKISEMI 15A,500V N-CHANNEL PLANAR STRIPE POWER MOSFETs

Features

- ※ Low ON Resistance
- ※ Low Gate Charge
- ※ Peak Current vs Pulse Width Curve
- ※ ESD Capability Improved
- ※ **100% Avalanche Tested**

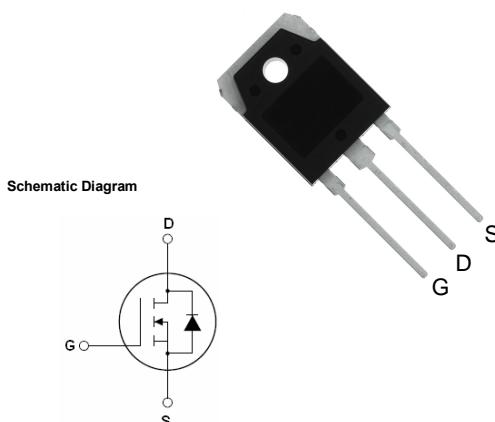
Application

- ※ Uninterruptible Power Supply(UPS)
- ※ LCD Panel Power
- ※ DC-AC Inverter,Amplifier and SMPS

Mechanical Data

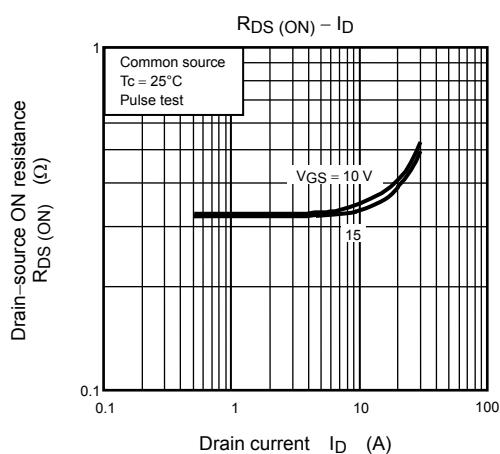
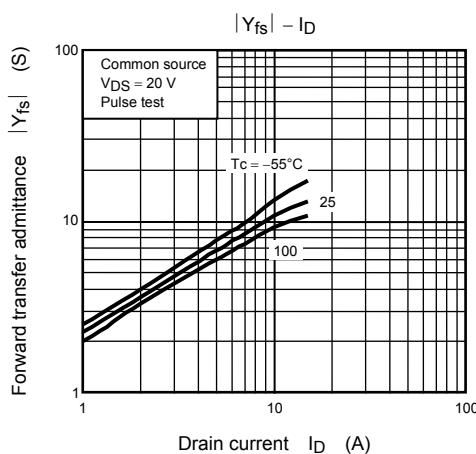
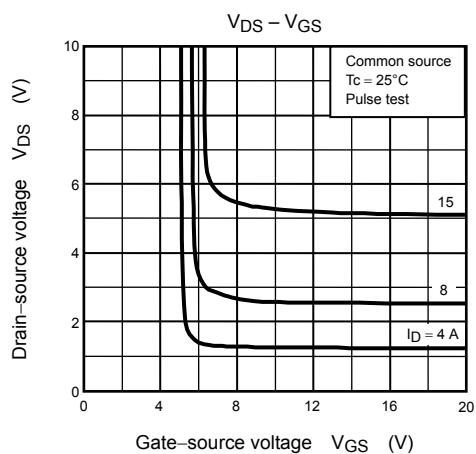
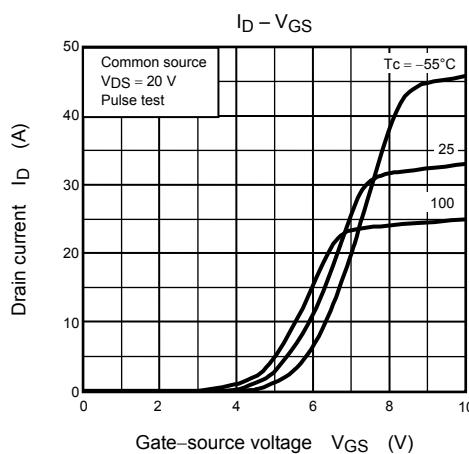
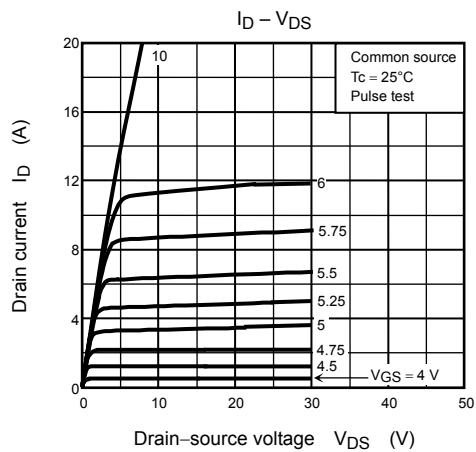
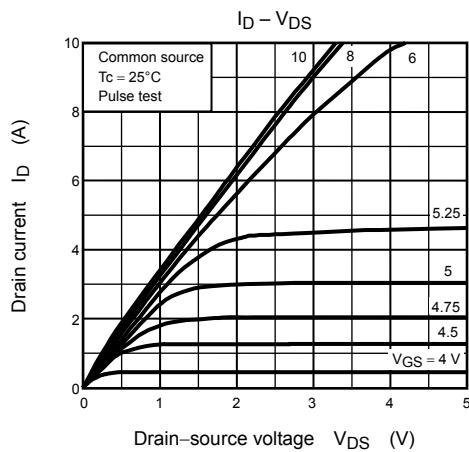
- ※ Case:TO-3P non-isolated package
- ※ Epoxy: UL 94V-0 rate flame retardant
- ※ Terminals: Solderable per MIL-STD-202 method 208
- ※ Polarity: As per configuration
- ※ Mounting position: Any
- ※ Weight: 6.0 gram approximately

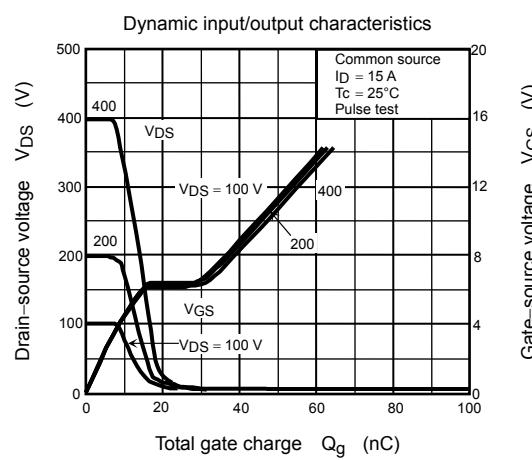
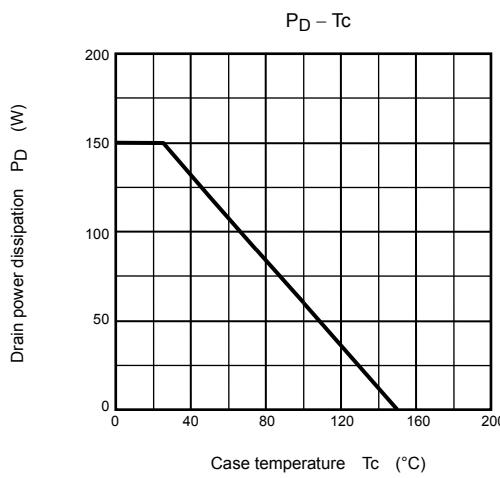
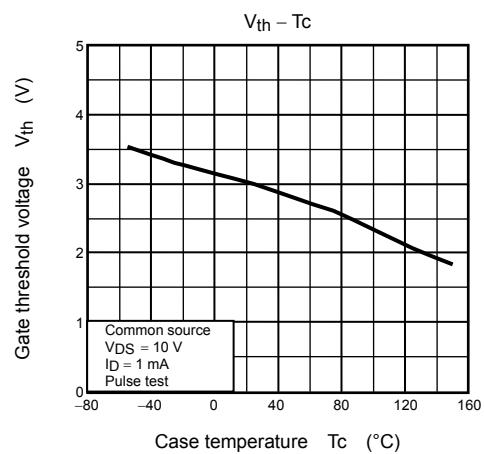
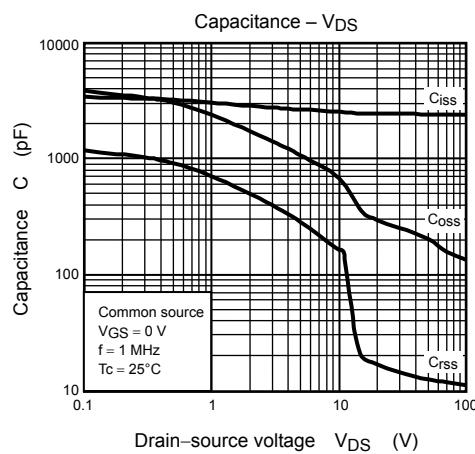
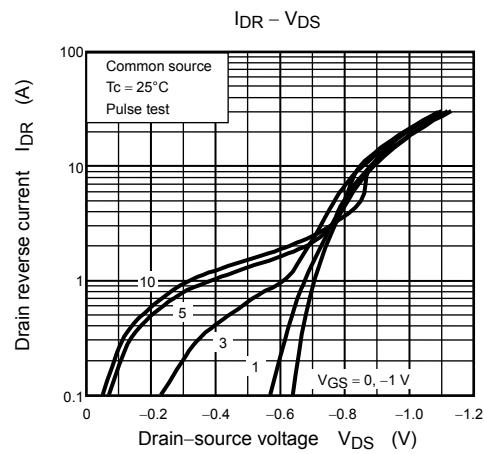
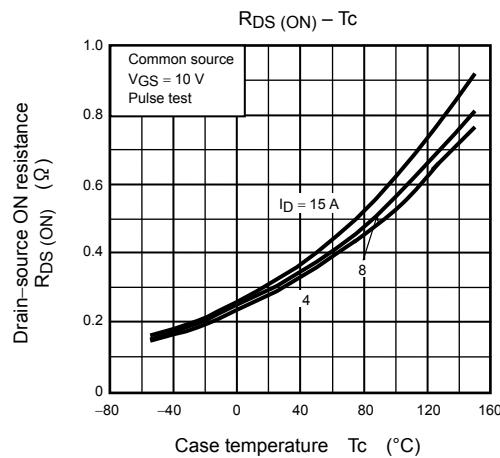
TO-3P pkg outline & internal configuration

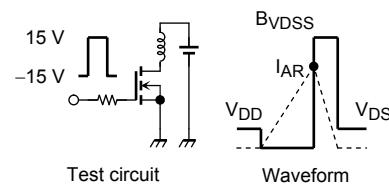
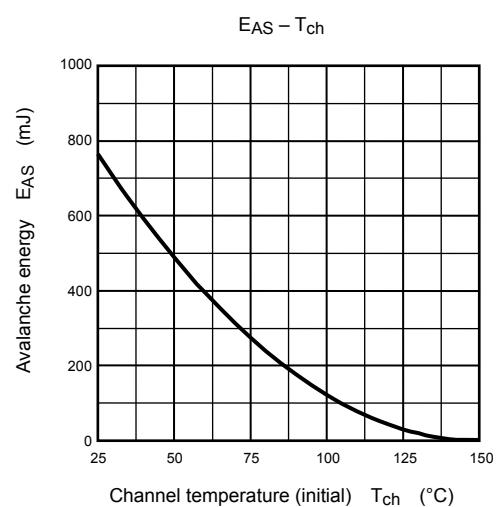
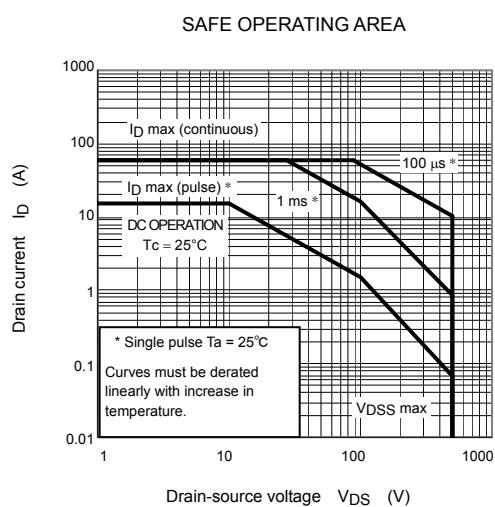
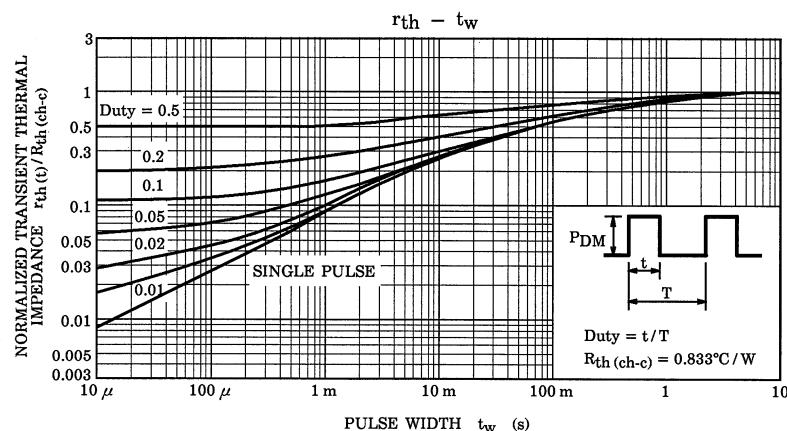


Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Drain-source voltage	V _{DSS}	500	V
Drain-gate voltage (R _{GS} = 20 kΩ)	V _{DGR}	500	V
Gate-source voltage	V _{GSS}	±30	V
Drain current	DC (Note 1)	I _D	A
	Pulse (Note 1)	I _{DP}	A
Drain power dissipation (T _c = 25°C)	P _D	150	W
Single-pulse avalanche energy (Note 2)	E _{AS}	765	mJ
Avalanche current	I _{AR}	15	A
Repetitive avalanche energy (Note 3)	E _{AR}	15	mJ
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C







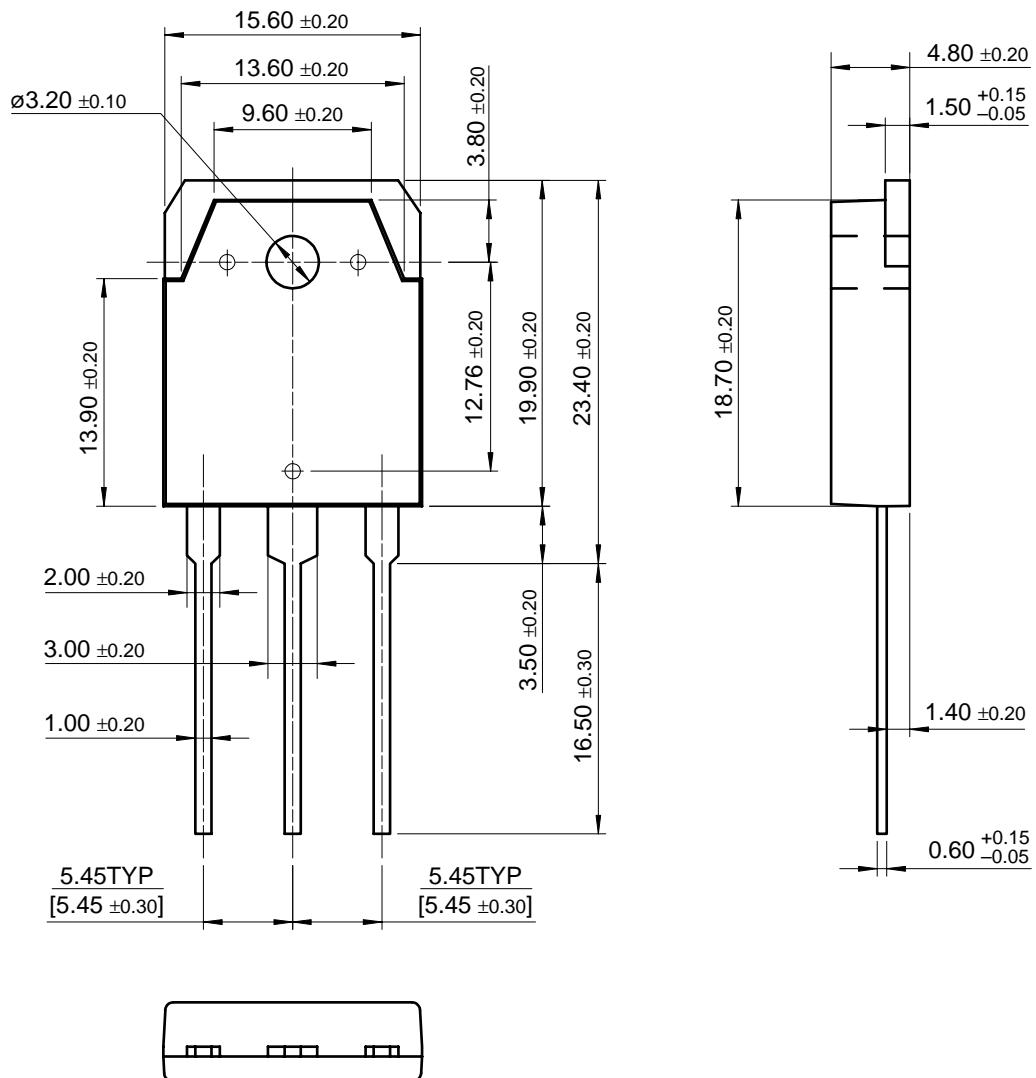
$$R_G = 25\ \Omega$$

$$V_{DD} = 90\ \text{V}, L = 5.78\ \text{mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

THINKI TO-3P Package Dimensions

TO-3PN-SQ/TO-3PB-SQ



Dimensions in Millimeters